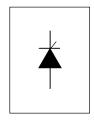
International Rectifier

SAFE**IR** Series 30TPS..

PHASE CONTROL SCR



 V_{T} < 1.3V @ 20A I_{TSM} = 300A V_{RRM} 800 to 1600V

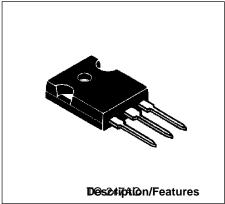
The 30TPS.. SAFE**IR** series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125°C junction temperature.

Typical applications are in input rectification (soft start) and these products are designed to be used with International Rectifier input diodes, switches and output rectifiers which are available in identical package outlines.

Major Ratings and Characteristics

Characteristics	30TPS	Units
I _{T(AV)} Sinusoidal	20	Α
waveform		
I _{RMS}	30	Α
V _{RRM} / V _{DRM}	up to 1600	٧
I _{TSM}	300	Α
V _T @ 20 A, T _J = 25°C	1.3	V
dv/dt	500	V/µs
di/dt	150	A/µs
T _J	-40 to 125	°C

Package Outline



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Voltage Ratings

Part Number	V _{RRM} /V _{DRM} , max. repetitive peak and off-state voltage V	V _{RSM} , maximum non repetitive peak reverse voltage V	I _{RRM} /I _{DRM} 125°C mA
30TPS08	800	900	10
30TPS12	1200	1300	
30TPS16	1600	1700	

Absolute Maximum Ratings

	Parameters	30TPS	Units		Conditions
I _{T(AV)}	Max. Average On-state Current	20	Α	@T _C =95°C,1	80° conduction half sine wave
I _{RMS}	Max. RMS On-state Current	30			
I _{TSM}	Max. Peak One Cycle Non-Repetitive	250		10ms Sine puls	se, rated V _{RRM} applied
	Surge Current	300		10ms Sine puls	se, no voltage reapplied
l ² t	Max. I ² tfor Fusing	310	A ² s	10ms Sine puls	se, rated V _{RRM} applied
		442		10ms Sine puls	se, no voltage reapplied
I ² √t	Max.I ² √t for Fusing	4420	A ² √s	t=0.1 to 10ms,	, no voltage reapplied
V_{TM}	Max. On-state Voltage Drop	1.3	V	@ 20A, T _J = 25	5°C
r _t	On-state Slope Resistance	12	mΩ	T _J = 125°C	
V _{T(TO)}	Threshold Voltage	1.0	٧		
I _{RM} /I _{DN}	Max.Reverse and Direct	0.5	mA	T _J = 25 °C	$V_R = \text{rated } V_{RRM} / V_{DRM}$
	Leakage Current	10		T _J = 125 °C	V _R = rated V _{RRM} , V _{DRM}
I _H	Max. Holding Current	100	mA	Anode Supply	v = 6V, Resistive load, Initial I _T =1A
IL	Max. Latching Current	200	mA	Anode Supply = 6V, Resistive load	
dv/dt	Max. Rate of Rise of off-state Voltage	500	V/µs		
di/dt	Max. Rate of Rise of turned-on Current	150	A/µs		

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Triggering

Parameters	30TPS	S Units	Conditions
P _{GM} Max. Peak Gate Power	8.0	W	
P _{G(AV)} Max. Average Gate Powe	r 2.0		
+ I _{GM} Max. Peak Positive Gate 0	Current 1.5	А	
- V _{GM} Max. Peak Negative Gate	Voltage 10	V	
I _{GT} Max. Required DC Gate C	Current 60	mA	Anode supply = 6V, resistive load, T _J = - 10°C
to Trigger	45		Anode supply = 6V, resistive load, T _J = 25°C
	20		Anode supply = 6V, resistive load, T _J = 125°C
V _{GT} Max. Required DC Gate V	oltage 2.5	V	Anode supply = 6V, resistive load, T _J = - 10°C
to Trigger	2.0		Anode supply = 6V, resistive load, T _J = 25°C
	1.0		Anode supply = 6V, resistive load, T _J = 125°C
V _{GD} Max. DC Gate Voltage not	to Trigger 0.25		T _J = 125°C, V _{DRM} = rated value
I _{GD} Max. DC Gate Current not	to Trigger 2.0	mA	T _J = 125°C, V _{DRM} = rated value

Switching

	Parameters	30TPS	Units	Conditions
t _{gt}	Typical Turn-on Time	0.9	μs	T _J = 25°C
t _{rr}	Typical Reverse Recovery Time	4		T _J = 125°C
tq	Typical Turn-off Time	110		

Thermal-Mechanical Specifications

	Parameters		30TPS	Units	Conditions
TJ	Max. Junction Temperature	Range	- 40 to 125	°C	
T _{stg}	Max. Storage Temperature	Range	- 40 to 125		
R _{thJC}	Max. Thermal Resistance J	unction	0.8	°C/W	DC operation
	to Case				
R _{thJA}	Max. Thermal Resistance J	unction	40		
	to Ambient				
R _{thCS}	Max. Thermal Resistance C	ase	0.2		Mounting surface, smooth and greased
	to Heatsink				
wt	Approximate Weight		6 (0.21)	g (oz.)	
Т	Mounting Torque	Min.	6 (5)	Kg-cm	
		Max.	12 (10)	(lbf-in)	
	Case Style		TO-24	7AC	Jedec (Modified)

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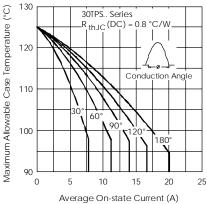


Fig. 1 - Current Rating Characteristics

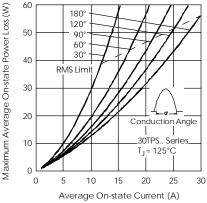


Fig. 3 - On-state Power Loss Characteristics

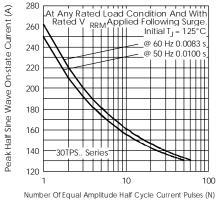


Fig. 5 - Maximum Non-Repetitive Surge Current

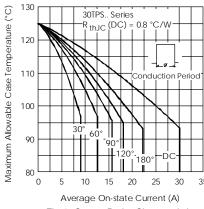


Fig. 2 - Current Rating Characteristics

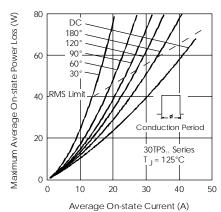
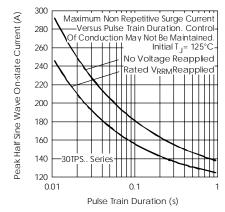


Fig. 4 - On-state Power Loss Characteristics



 $Fig.\,6-Maximum\,Non-Repetitive\,Surge\,Current$

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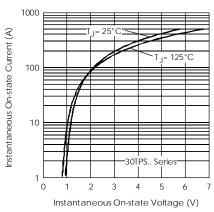
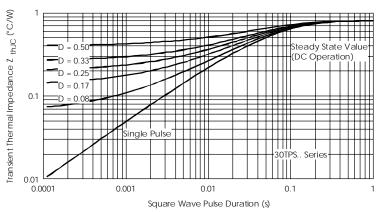


Fig. 7 - On-state Voltage Drop Characteristics



 $Fig.\,8-Thermal\,Impedance\,Z_{thJC}Characteristics$

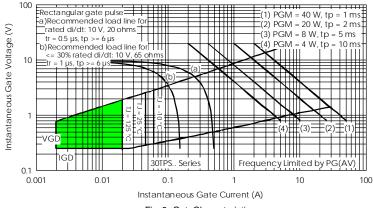
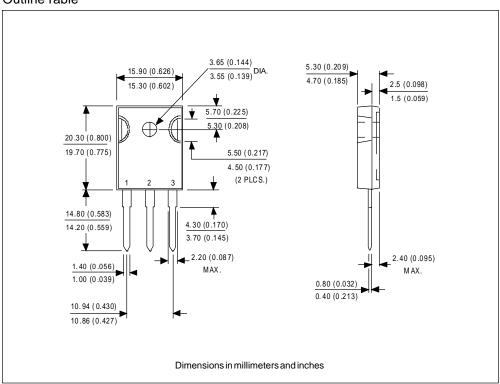


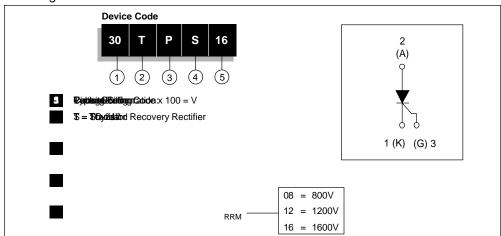
Fig. 9 - GateCharacteristics

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Outline Table



Ordering Information Table



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